



做中国自主知识产权核心处理器  
MCU/DSP/CPU芯片级大脑领导者

# 深圳市航顺芯片技术研发有限公司 航顺浩瀚处理器（广州）有限公司

国家高新技术企业 深圳龙华2017年八大重点签约引进企业  
航顺芯片32位通用MCU之M0 M3 M4世界级超低功耗  
性能超稳定 开发工具全兼容进口 软硬件全兼容进口

## 航顺技术参数 型号:HK93C46/HK93C56/HK93C66

### 公司介绍

上海航顺微电子有限公司创建于2006年。航顺坚持研发自主产品，推广自主品牌，经过多年的发展，航顺HS在集成电路行业中已具有一定的品牌影响力，市场占有率。为提高工作效率，更方便服务各地区客户，于2008年相继在香港，深圳，浙江设立仓库。基本做到航顺所有自主产品长期现货，长期库存，当天发货，送货上门。上海航顺微电子有限公司拥有一支具有丰富专业知识和经验的团队。在公司发展历程中积累了丰富的产品设计研发经验，并形成了完善的产销协作体系，也打下了良好的生产管理基础；公司研发设计、生产、管理有序，产品质量把关严密。上海航顺微电子有限公司将以“专业、专注、诚信”的企业精神。专注发展HS航顺自主品牌。积极面对未来，不断创新进取，以雄厚的技术实力，优良的服务品质，致力于打造一流的集成电路设计企业，立志将中国芯“HS航顺品牌”遍及全世界，服务全人类。

上海航顺微电子有限公司在专注发展的多年中，自主研发HS航顺品牌多个系列产品：电源管理类低压差稳压电路和电压检测电路；非易失性存储产品EEPROM芯片24CXX系列；LCD液晶显示驱动；DCDC升压；LED数码管驱动74HC系列等。这些产品的特点是：抗干扰能力强，抗静电能力强，电参数性能稳定，上机率高，工作失效率低，并且品种规格齐全，封装形式多样，性能良好，质量稳定。HS产品大量被运用到家电、照明、消费类电子、通讯、汽车防盗、游戏产业、机电控制、医疗电子等多个领域，并且有不错的市场占有率，赢得广泛的市场认可和良好的声誉。

公司将不断打造自己的HS航顺品牌，拓宽销售市场，让客户用得满意，用的放心。

我们的宗旨：“一专业专注诚信一”

我们的承诺：“一不以牺牲质量而节约成本，但努力在质量可靠的前提下降低价格。成为集成电路行业中---中国自主的名族品牌一”

我们的目标：“一立志将中国芯“HS品牌”遍及全世界服务全人类一”



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# 3-Wire Serial EEPROM

## 1K, 2K and 4Kbit (8-bit or 16-bit wide)

### FEATURES

- Standard Voltage and Low Voltage Operation:
  - HK93C46/56/66:  $V_{CC} = 1.8V$  to  $5.5V$
- User Selectable Internal Organization:
  - HK93C46: 128 x 8 or 64 x 16
  - HK93C56: 256 x 8 or 128 x 16
  - HK93C66: 512 x 8 or 256 x 16
- 2 MHz Clock Rate (5V) Compatibility.
- Industry Standard 3-wire Serial Interface.
- Self-Timed ERASE/WRITE Cycles (5ms max including auto-erase).
- Automatic ERAL before WRAL.
- Sequential READ Function.
- High Reliability: Typical 1 Million Erase/Write Cycle Endurance.
- 100 Years Data Retention.
- Industrial Temperature Range ( $-40^{\circ}C$  to  $85^{\circ}C$ ).
- Standard 8-pin PDIP/SOIC/TSSOP Pb-free Packages.

### DESCRIPTION

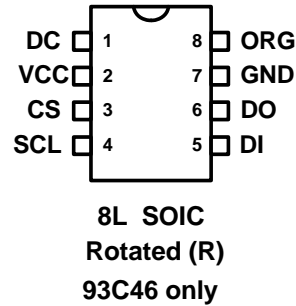
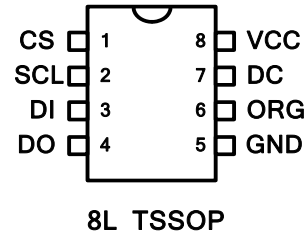
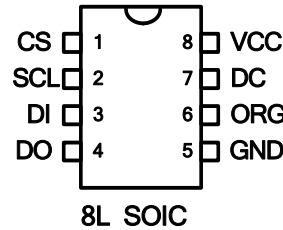
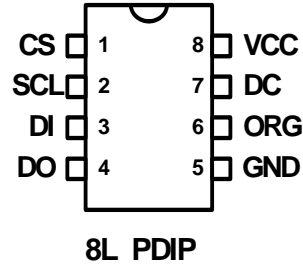
The HK93C46/56/66 series are 1024/2048/4096 bits of serial Electrical Erasable and Programmable Read Only Memory, commonly known as EEPROM. They are organized as 64/128/256 words of 16 bits each when the ORG pin is connected to VCC (or unconnected) and 128/256/512 words of 8 bits (1 byte) each when the ORG pin is tied to ground. The devices are fabricated with proprietary advanced CMOS process for low power and low voltage applications. These devices are available in standard 8-lead PDIP, 8-lead JEDEC SOIC and 8-lead TSSOP packages. Our extended  $V_{CC}$  range (1.8V to 5.5V) devices enables wide spectrum of applications.

The HK93C46/56/66 is enabled through the Chip Select pin (CS), and accessed via a 3-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SCL). Upon receiving a READ instruction at DI, the address is decoded and the data is clocked out serially on the data output pin DO. The WRITE cycle is completely self-timed and no separate ERASE cycle is required before WRITE. The WRITE cycle is only enabled when the part is in the ERASE/WRITE ENABLE state. Once a device begins its self-timed program procedure, the data out pin (DO) can indicate the READY/BUSY status by rising chip select (CS).

## PIN CONFIGURATION

Pin Name	Pin Function
CS	Chip Select
SCL	Serial Clock
DI	Serial Data Input
DO	Serial Data Output
ORG	Internal Organization
DC	Don't Connect
VCC	Power Supply
GND	Ground

All these packaging types come in Pb-free certified.

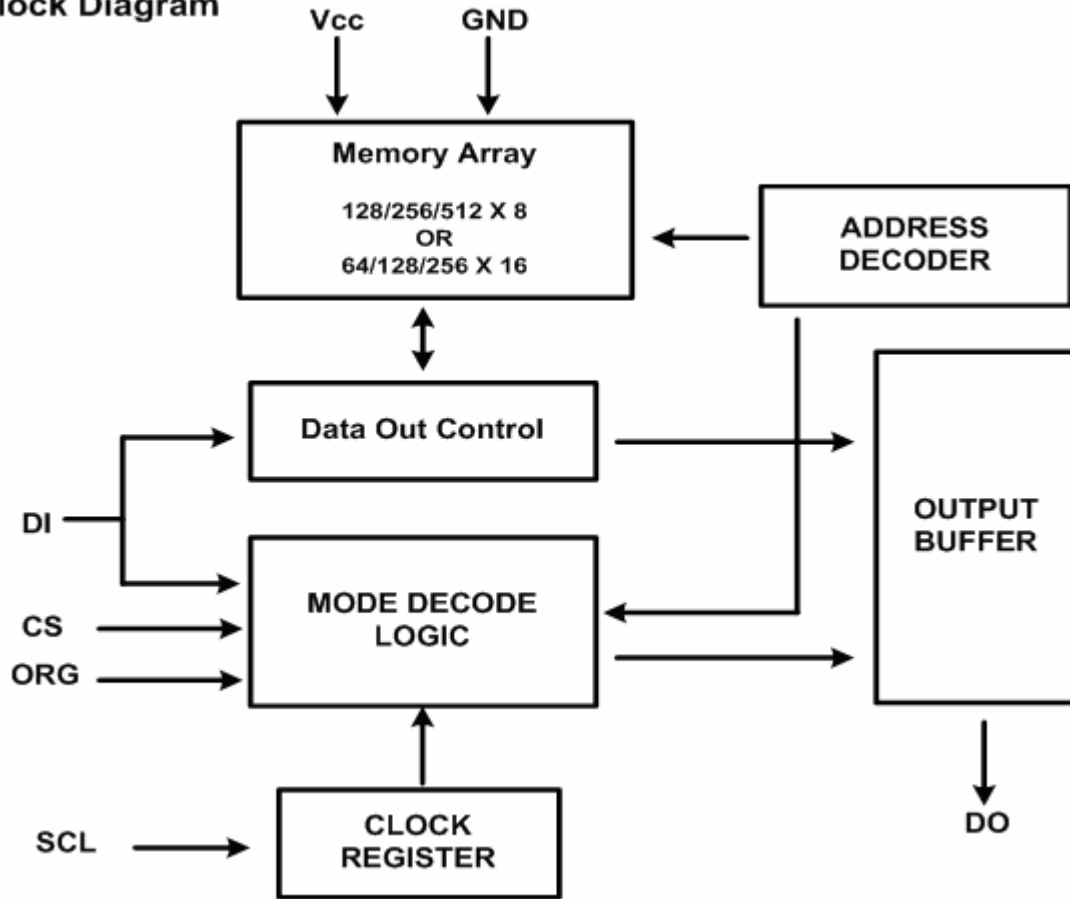


## ABSOLUTE MAXIMUM RATINGS

Industrial operating temperature:	-40°C to 85°C
Storage temperature:	-50°C to 125°C
Input voltage on any pin relative to ground:	-0.3V to $V_{CC} + 0.3V$
Maximum voltage:	8V

\* Stresses exceed those listed under “Absolute Maximum Rating” may cause permanent damage to the device. Functional operation of the device at conditions beyond those listed in the specification is not guaranteed. Prolonged exposure to extreme conditions may affect device reliability or functionality.

## Block Diagram



## PIN DESCRIPTIONS

### (A) SERIAL CLOCK (SCL)

The rising edge of this SCL input is to latch data into the EEPROM device while the rising edge of this clock is to clock data out of the EEPROM device.

### (B) CHIP SELECT (CS)

This is the chip select input signal for the serial EEPROM device.

### (C) SERIAL DATA INPUT (DI)

This is data input signal for the serial device.

### (D) SERIAL DATA OUTPUT (DO)

This is data output signal for the serial device.

### (E) INTERNAL ORGANIZATION (ORG)

This is internal organization input signal for the serial EEPROM device. When the ORG pin is connected to VCC or unconnected the EEPROM is organized as 64/128/256 word of 16 bits each and when ORG pin is connected to ground the EEPROM is organized as 128/256/512 byte of 8 bits each. Typically, these signals are hardwired to either  $V_{IH}$  or  $V_{IL}$ . If left unconnected, they are internally recognized as  $V_{IH}$ .



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## MEMORY ORGANIZATION

The HK93C46/56/66 memory is organized either as bytes (x8) or as words (x16). If Internal Organization (ORG) is unconnected (or connected to VCC) the words (x16) organization is selected; When Internal Organization is connected to ground the bytes (x8) organization is selected.

## INSTRUCTION SET for the HK93C46

Instruction	SB	Op Code	Address		Data		Comments
			x 8	x 16	x 8	x 16	
READ	1	10	A <sub>6</sub> - A <sub>0</sub>	A <sub>5</sub> - A <sub>0</sub>			Reads data stored in memory, at specified address.
EWEN	1	00	11xxxxx	11xxxx			Write enable must precede all programming modes.
EWDS	1	00	00xxxxx	00xxxx			Disables all programming instructions.
ERASE	1	11	A <sub>6</sub> - A <sub>0</sub>	A <sub>5</sub> - A <sub>0</sub>			Erase memory location A <sub>n</sub> - A <sub>0</sub> .
WRITE	1	01	A <sub>6</sub> - A <sub>0</sub>	A <sub>5</sub> - A <sub>0</sub>	D <sub>7</sub> - D <sub>0</sub>	D <sub>15</sub> - D <sub>0</sub>	Writes memory location A <sub>n</sub> - A <sub>0</sub> .
ERAL	1	00	10xxxxx	10xxxx			Erases all memory locations.
WRAL	1	00	01xxxxx	01xxxx	D <sub>7</sub> - D <sub>0</sub>	D <sub>15</sub> - D <sub>0</sub>	Writes all memory locations.

## INSTRUCTION SET for the HK93C56 and HK93C66

Instruction	SB	Op Code	Address		Data		Comments
			x 8	x 16	x 8	x 16	
READ	1	10	A <sub>8</sub> - A <sub>0</sub>	A <sub>7</sub> - A <sub>0</sub>			Reads data stored in memory, at specified address.
EWEN	1	00	11xxxxxxxx	11xxxxxxxx			Write enable must precede all programming modes.
EWDS	1	00	00xxxxxxxx	00xxxxxxxx			Disables all programming instructions.
ERASE	1	11	A <sub>8</sub> - A <sub>0</sub>	A <sub>7</sub> - A <sub>0</sub>			Erase memory location A <sub>n</sub> - A <sub>0</sub> .
WRITE	1	01	A <sub>8</sub> - A <sub>0</sub>	A <sub>7</sub> - A <sub>0</sub>	D <sub>7</sub> - D <sub>0</sub>	D <sub>15</sub> - D <sub>0</sub>	Writes memory location A <sub>n</sub> - A <sub>0</sub> .
ERAL	1	00	10xxxxxxxx	10xxxxxxxx			Erases all memory locations.
WRAL	1	00	01xxxxxxxx	01xxxxxxxx	D <sub>7</sub> - D <sub>0</sub>	D <sub>15</sub> - D <sub>0</sub>	Writes all memory locations.

### (A) START BIT (SB)

Each instruction is preceded by a rising edge on Chip Select (CS) with Serial Clock (SCL) being held Low.

### (B) OPERATION CODE (OP-CODE)

Two op-code bits, read on Serial Data Input (DI) during the rising edge of Serial Clock (SCL).

### (C) ADDRESS

The address bits of the byte or word that is to be accessed. For the HK93C46, the address is made up of 6 bits for the x16 organization or 7 bits for x8 organization. For the HK93C56, the address is made up of 7 bits for the x16 organization or 8 bits for x8 organization. For the HK93C66, the address is made up of 8 bits for the x16 organization or 9 bits for x8 organization.

### (D) DATA

The data bits of the byte or word that is to be accessed. For the HK93C46/56/66, the data is made up of 16 bits (word) for the x16 organization or 8 bits (byte) for x8 organization.



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## INSTRUCTION SETS DESCRIPTION

### (A) READ

The Read (READ) instruction contains the Address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that when a dummy bit (logic “0”) precedes the 8- or 16-bit data output string.

### (B) ERASE/WRITE ENABLE

To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the Erase/Write Enable state, programming remains enabled until an Erase/Write Disable (EWDS) instruction is executed or  $V_{CC}$  power is removed from the part.

### (C) ERASE/WRITE DISABLE

To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

### (D) ERASE

The Erase (ERASE) instruction programs all bits in the specified memory location to the logical “1” state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic “1” at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.

### (E) WRITE

The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle,  $t_{WP}$ , starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic “0” at DO indicates that programming is still in progress. A logic “1” indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A READY/BUSY status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle,  $t_{WP}$ .

### (F) ERASE ALL

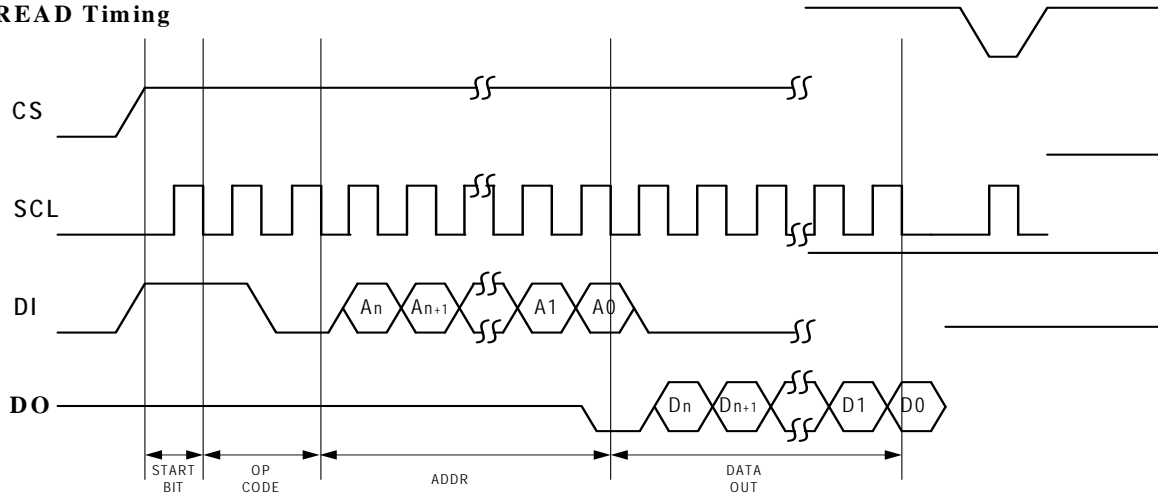
The Erase All (ERAL) instruction programs every bit in the memory array to the logic “1” state and is primarily used for testing purposes. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The ERAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

### (G) WRITE ALL

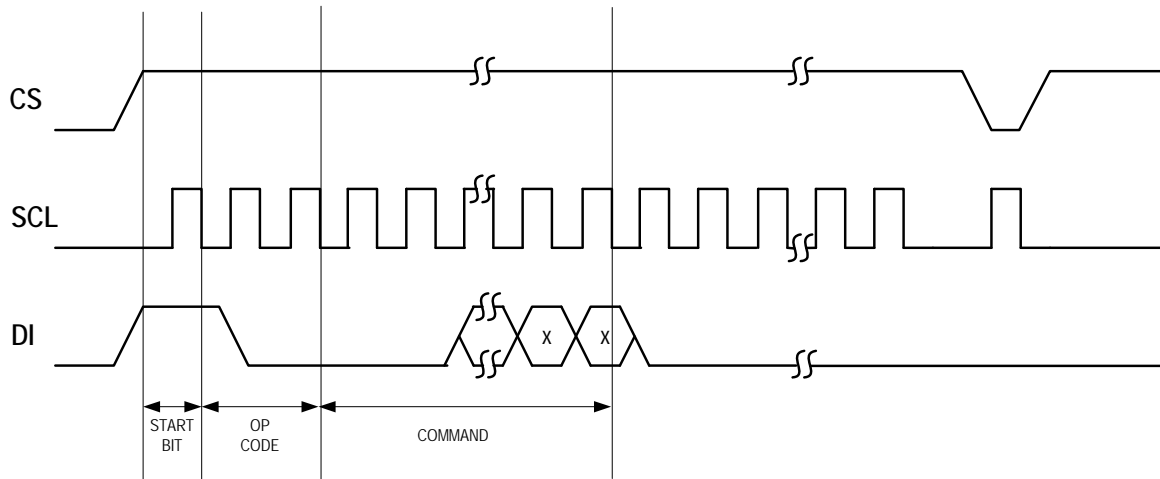
The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The WRAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

## Timing Diagrams

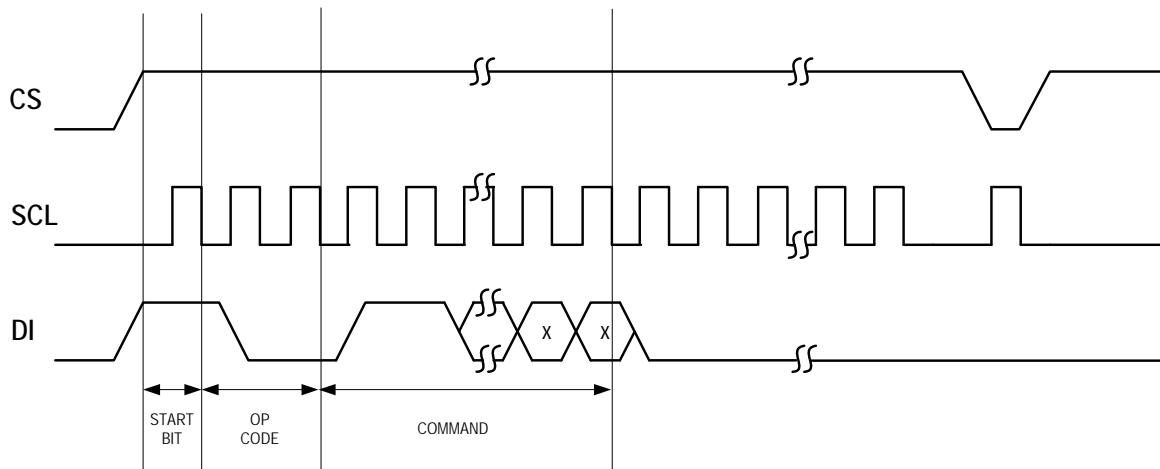
### READ Timing



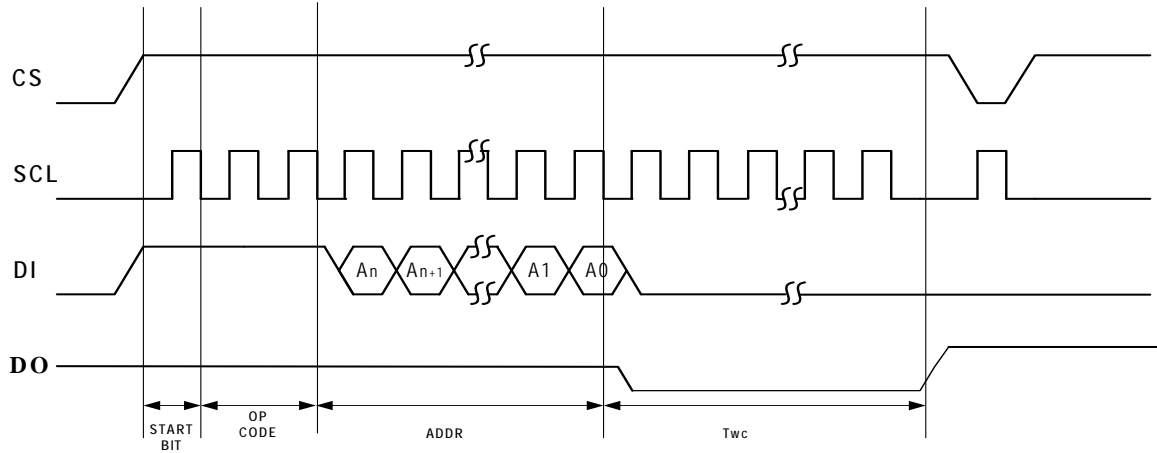
### EWDS Timing



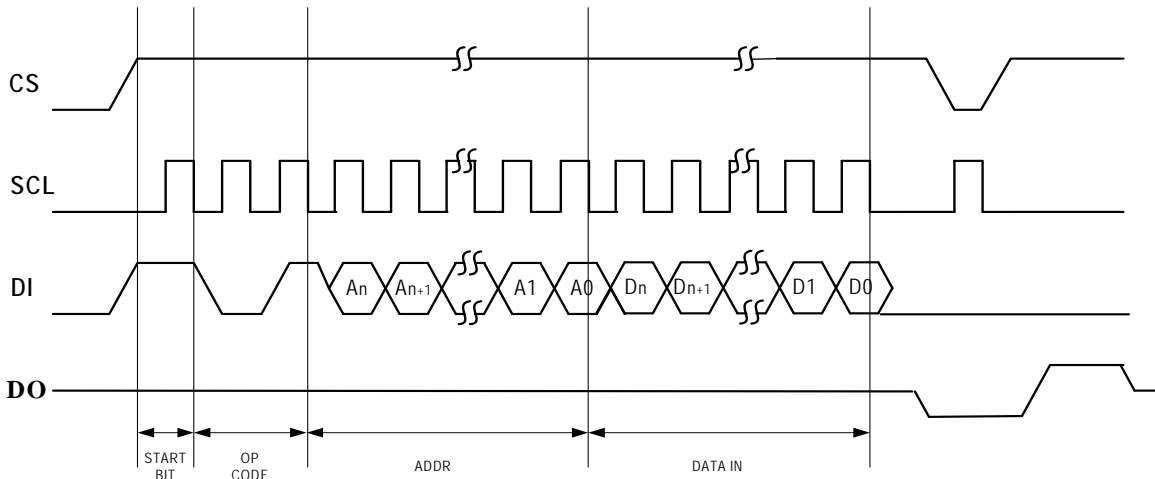
### EWEN Timing



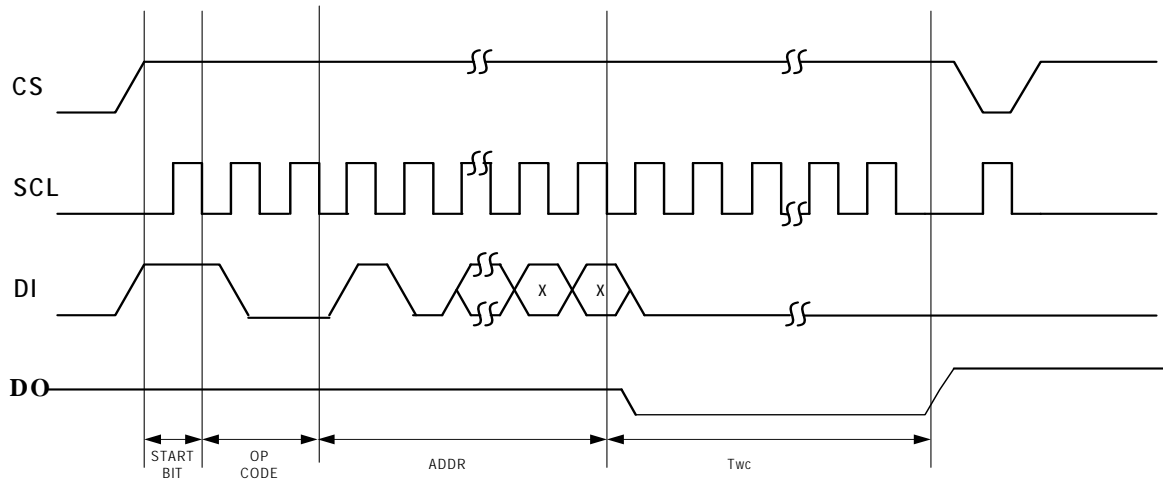
### ERASE Timing



### WRITE Timing

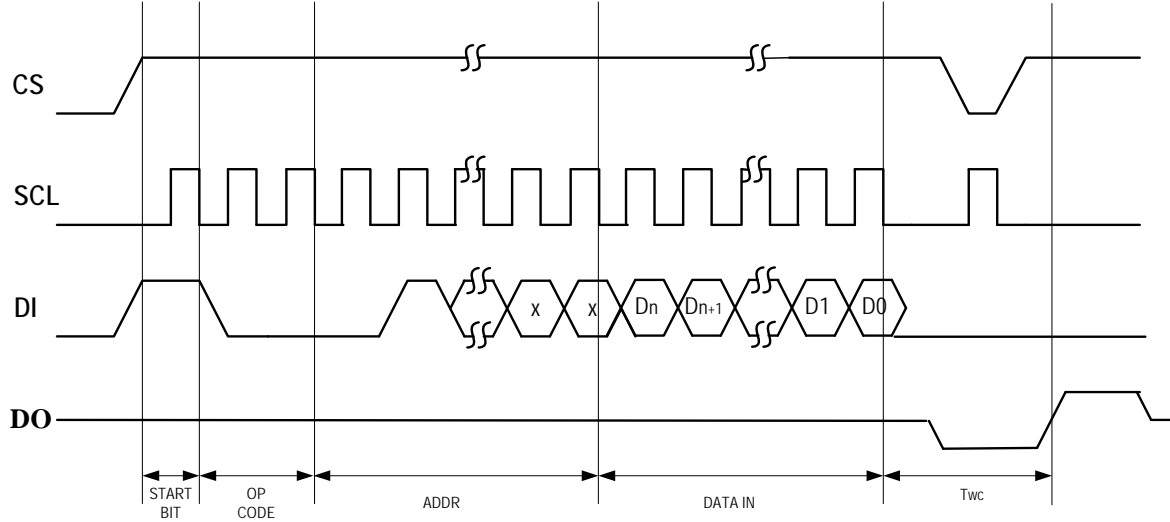


### ERAL Timing (1)



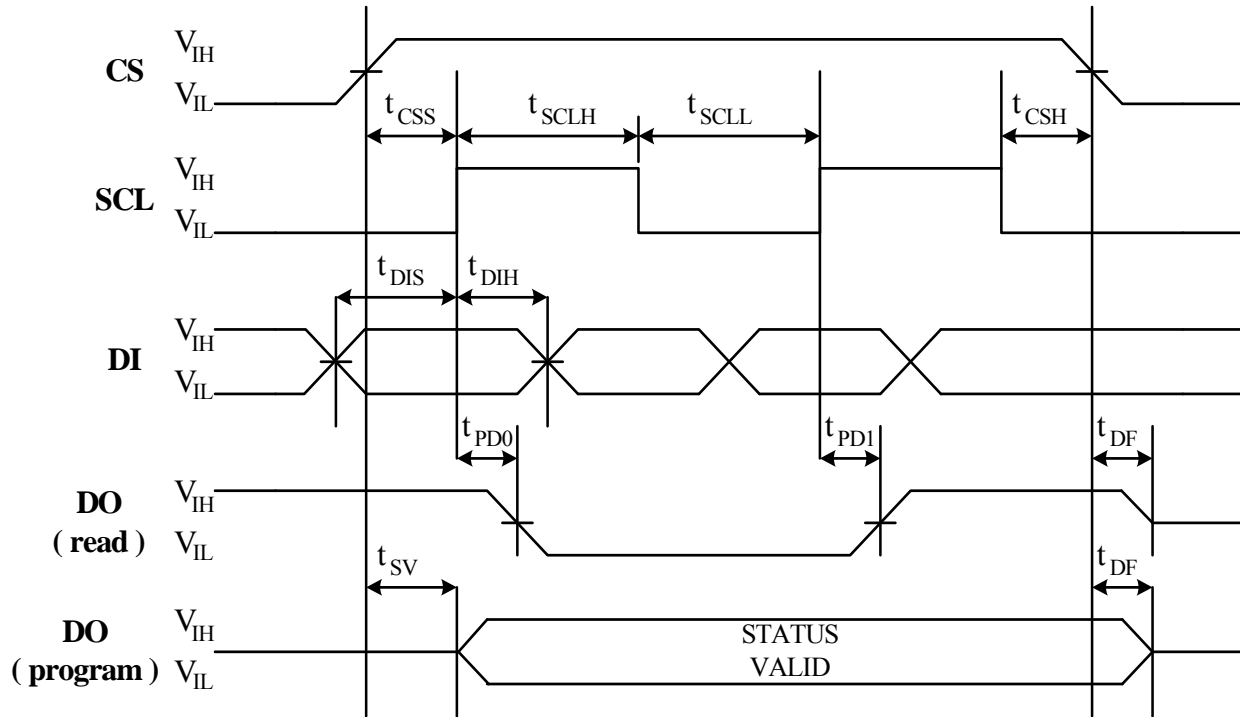


### WRAL Timing (2)



Note : 1. Valid only at  $V_{CC}=4.5V$  to  $5.5V$   
2. Valid only at  $V_{CC}=4.5V$  to  $5.5V$

### Synchronous Data Timing



## AC CHARACTERISTICS

Applicable over recommended operating range from:  $T_{AI} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = +1.8\text{V}$  to  $+5.5\text{V}$ ,  $T_{AC} = 0^{\circ}\text{C}$  to  $+70^{\circ}\text{C}$ ,  $V_{CC} = +1.8\text{V}$  to  $+5.5\text{V}$  (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
$f_{SCL}$	SCL Clock Frequency	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	0 0 0		2 1 0.25	MHz
$t_{SCLH}$	SCL High Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	250 250 1000			ns
$t_{SCLL}$	SCL Low Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	250 250 1000			ns
$t_{CS}$	Minimum CS Low Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	250 250 1000			ns
$t_{CSS}$	CS Setup Time	Relative to SCL	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	50 50 200		ns
$t_{DIS}$	DI Setup Time	Relative to SCL	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	100 100 400		ns
$t_{CSH}$	CS Hold Time	Relative to SCL		0		ns
$t_{DIH}$	DI Hold Time	Relative to SCL	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$	100 100 400		ns
$t_{PD1}$	Output Delay to '1'	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$		250 250 1000	ns
$t_{PDO}$	Output Delay to '0'	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$		250 250 1000	ns
$t_{SV}$	CS to Status Valid	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$		250 250 1000	ns
$t_{DF}$	CS to DO in High Impedance	AC Test $CS = V_{IL}$	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ $2.7\text{V} \leq V_{CC} \leq 5.5\text{V}$ $1.8\text{V} \leq V_{CC} \leq 5.5\text{V}$		100 100 400	ns
$t_{WC}$	Write Cycle Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		3	10	ms



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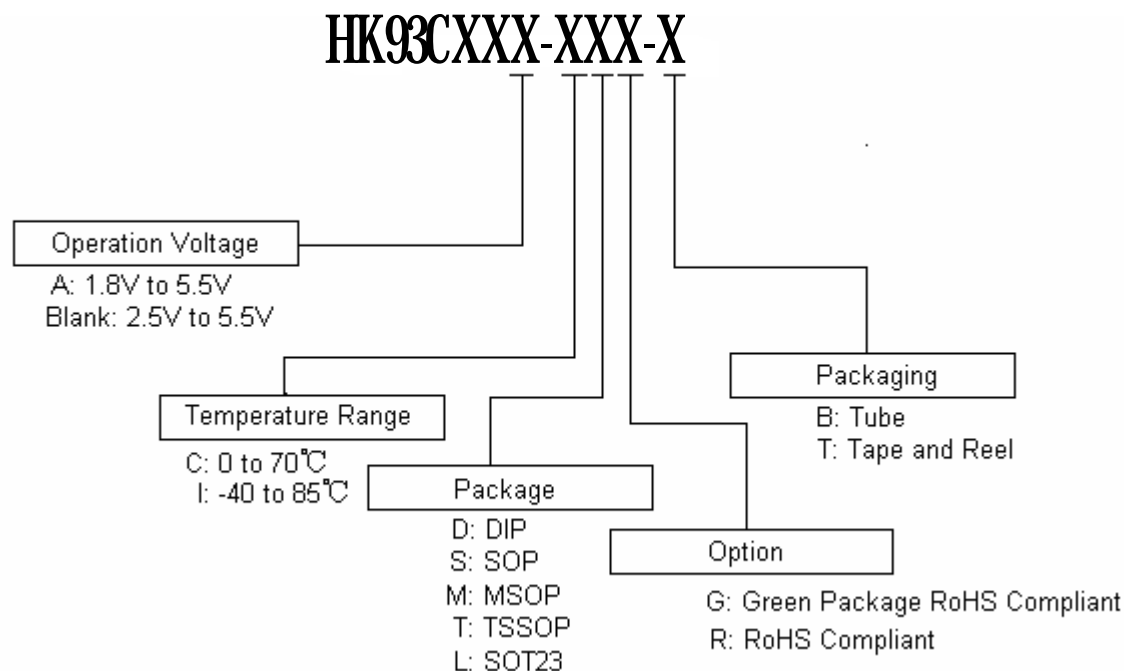
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## DC CHARACTERISTICS

Applicable over recommended operating range from  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = \text{As Specified}$ ,  $CL = 1$  TTL Gate and  $100\text{ pF}$  (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
$V_{CC1}$	Supply Voltage		1.8		5.5	V
$V_{CC2}$	Supply Voltage		2.5		5.5	V
$V_{CC3}$	Supply Voltage		2.7		5.5	V
$V_{CC4}$	Supply Voltage		4.5		5.5	V
$I_{CC}$	Supply Current	$V_{CC} = 5.0\text{V}$	READ at 1.0 MHz	0.5	2.0	mA
			WRITE at 1.0 MHz	0.5	2.0	mA
$I_{SB1}$	Standby Current	$V_{CC} = 1.8\text{V}$	$CS = 0\text{V}$	0	0.1	$\mu\text{A}$
$I_{SB2}$	Standby Current	$V_{CC} = 2.5\text{V}$	$CS = 0\text{V}$	6.0	10.0	$\mu\text{A}$
$I_{SB3}$	Standby Current	$V_{CC} = 2.7\text{V}$	$CS = 0\text{V}$	6.0	10.0	$\mu\text{A}$
$I_{SB4}$	Standby Current	$V_{CC} = 5.0\text{V}$	$CS = 0\text{V}$	17	30	$\mu\text{A}$
$I_{IL}$	Input Leakage	$V_{in} = 0\text{V}$ to $V_{CC}$		0.1	1.0	$\mu\text{A}$
$I_{OL}$	Output Leakage	$V_{in} = 0\text{V}$ to $V_{CC}$		0.1	1.0	$\mu\text{A}$
$V_{IL1}^{(1)}$ $V_{IH1}^{(1)}$	Input Low Voltage Input High Voltage	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		-0.6 2.0	0.8 $V_{CC} + 1$	V
$V_{IL2}^{(1)}$ $V_{IH2}^{(1)}$	Input Low Voltage Input High Voltage	$1.8\text{V} \leq V_{CC} \leq 2.7\text{V}$		-0.6 $V_{CC} \times 0.7$	$V_{CC} \times 0.3$ $V_{CC} + 1$	V
$V_{OL1}$	Output Low Voltage		$I_{OL} = 2.1\text{ mA}$		0.4	V
$V_{OH1}$	Output High Voltage	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	$I_{OH} = -0.4\text{ mA}$	2.4		V
$V_{OL12}$	Output Low Voltage		$I_{OL} = 0.15\text{ mA}$		0.2	V
$V_{OH2}$	Output High Voltage	$1.8\text{V} \leq V_{CC} \leq 2.7\text{V}$	$I_{OH} = -100\ \mu\text{A}$	$V_{CC} - 0.2$		V

## ORDER CODE:



## ORDER INFORMATION

Order code	Vcc	Temperature Range	Package	Option	Packaging	PIN
HK93C46-CDG-B	1.8v-5.5v	0-70 <sup>0</sup> C	DIP8	Green Package	Tube	
HK93C46-CDR-B	1.8v-5.5v	0-70 <sup>0</sup> C	DIP8	RoHS	Tube	
HK93C46-IDG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	DIP8	Green Package	Tube	
HK93C46-IDR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	DIP8	RoHS	Tube	
HK93C46-CSG-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	Tube	
HK93C46-CSG-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	T/R	
HK93C46-CSR-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	Tube	
HK93C46-CSR-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	T/R	
HK93C46-ISG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	Tube	
HK93C46-ISG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	T/R	
HK93C46-ISR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	Tube	
HK93C46-ISR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	T/R	



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MCU/DSP/CPU芯片级大脑领导者

国家高新技术企业 深圳龙华2017年八大重点签约引进企业  
航顺芯片32位通用MCU之M0 M3 M4世界级超低功耗  
性能超稳定 开发工具全兼容进口 软硬件全兼容进口

Order code	Vcc	Temperature Range	Package	Option	Packaging	PIN
HK 93C46RA-CSG-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	Tube	Rotated
HK 93C46RA-CSG-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	T/R	Rotated
HK 93C46RA-CSR-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	Tube	Rotated
HK 93C46RA-CSR-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	T/R	Rotated
HK93C46RA-ISG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	Tube	Rotated
HK93C46RA-ISG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	T/R	Rotated
HK93C46RA-ISR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	Tube	Rotated
HK93C46RA-ISR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	T/R	Rotated
HK93C46-CTG-B	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	Green Package	Tube	
HK93C46-CTG-T	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	Green Package	T/R	
HK93C46-CTR-B	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	RoHS	Tube	
HK93C46-CTR-T	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	RoHS	T/R	
HK93C46-ITG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	Green Package	Tube	
HK93C46-ITG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	Green Package	T/R	
HK93C46-ITR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	RoHS	Tube	
HK93C46-ITR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	RoHS	T/R	



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性能超稳定 开发工具全兼容进口 软硬件全兼容进口

## ORDER INFORMATION (CONTINUED)

Order code	Vcc	Temperature Range	Package	Option	Packaging
HK93C56-CDG-B	1.8v-5.5v	0-70 <sup>0</sup> C	DIP8	Green Package	Tube
HK93C56-CDR-B	1.8v-5.5v	0-70 <sup>0</sup> C	DIP8	RoHS	Tube
HK93C56-IDG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	DIP8	Green Package	Tube
HK93C56-IDR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	DIP8	RoHS	Tube
HK93C56-CSG-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	Tube
HK93C56-CSG-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	T/R
HK93C56-CSR-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	Tube
HK93C56-CSR-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	T/R
HK93C56-ISG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	Tube
HK93C56-ISG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	T/R
HK93C56-ISR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	Tube
HK93C56-ISR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	T/R
HK93C56-CTG-B	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	Green Package	Tube
HK93C56-CTG-T	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	Green Package	T/R
HK93C56-CTR-B	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	RoHS	Tube
HK93C56-CTR-T	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	RoHS	T/R
HK93C56-ITG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	Green Package	Tube
HK93C56-ITG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	Green Package	T/R
HK93C56-ITR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	RoHS	Tube
HK93C56-ITR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	RoHS	T/R



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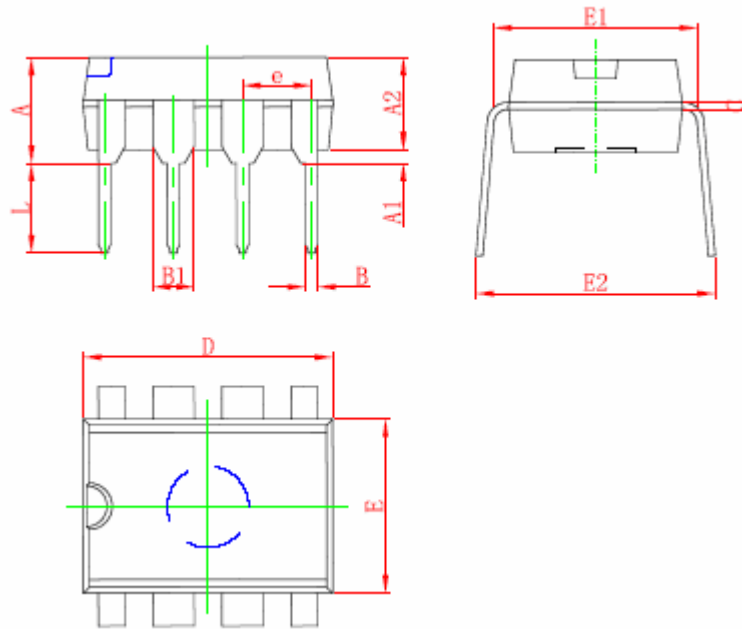
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## ORDER INFORMATION (CONTINUED)

Order code	Vcc	Temperature Range	Package	Option	Packaging
HK93C66-CDG-B	1.8v-5.5v	0-70 <sup>0</sup> C	DIP8	Green Package	Tube
HK93C66-CDR-B	1.8v-5.5v	0-70 <sup>0</sup> C	DIP8	RoHS	Tube
HK93C66-IDG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	DIP8	Green Package	Tube
HK93C66-IDR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	DIP8	RoHS	Tube
HK93C66-CSG-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	Tube
HK93C66-CSG-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	Green Package	T/R
HK93C66-CSR-B	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	Tube
HK93C66-CSR-T	1.8v-5.5v	0-70 <sup>0</sup> C	SOP8	RoHS	T/R
HK93C66-ISG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	Tube
HK93C66-ISG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	Green Package	T/R
HK93C66-ISR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	Tube
HK93C66-ISR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	SOP8	RoHS	T/R
HK93C66-CTG-B	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	Green Package	Tube
HK93C66-CTG-T	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	Green Package	T/R
HK93C66-CTR-B	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	RoHS	Tube
HK93C66-CTR-T	1.8v-5.5v	0-70 <sup>0</sup> C	TSSOP8	RoHS	T/R
HK93C66-ITG-B	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	Green Package	Tube
HK93C66-ITG-T	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	Green Package	T/R
HK93C66-ITR-B	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	RoHS	Tube
HK93C66-ITR-T	1.8v-5.5v	-40-85 <sup>0</sup> C	TSSOP8	RoHS	T/R

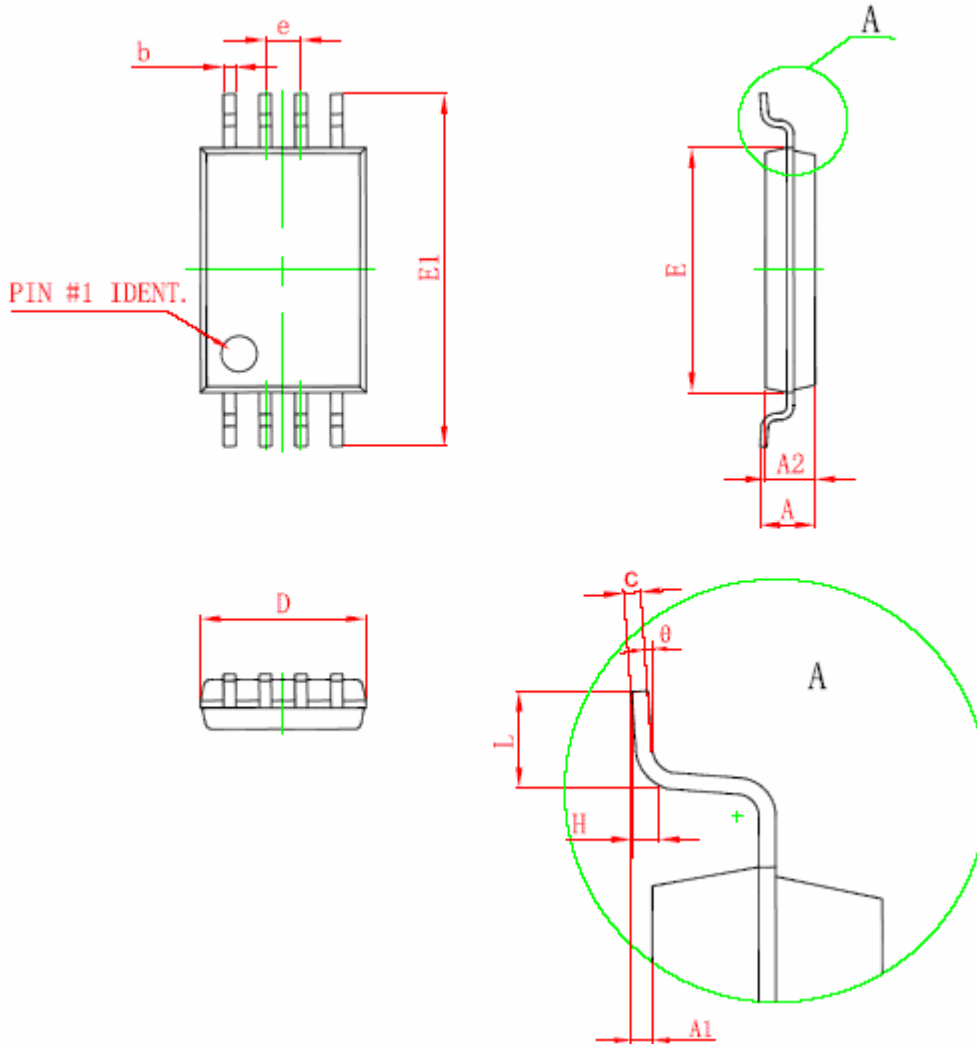
## DIP8 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.710	4.310	0.146	0.170
A1	0.510		0.020	
A2	3.200	3.600	0.126	0.142
B	0.380	0.570	0.015	0.022
B1	1.524 (BSC)		0.060 (BSC)	
C	0.204	0.360	0.008	0.014
D	9.000	9.400	0.354	0.370
E	6.200	6.600	0.244	0.260
E1	7.320	7.920	0.288	0.312
e	2.540 (BSC)		0.100 (BSC)	
L	3.000	3.600	0.118	0.142
E2	8.400	9.000	0.331	0.354

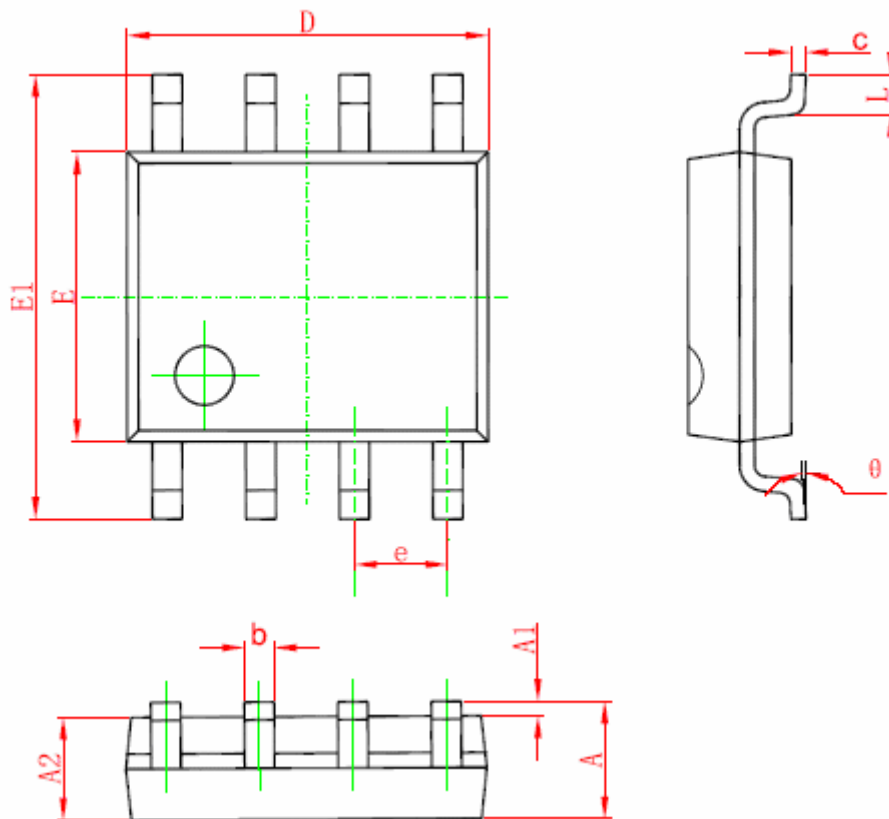


## TSSOP8 PACKAGE OUTLINE DIMENSIONS



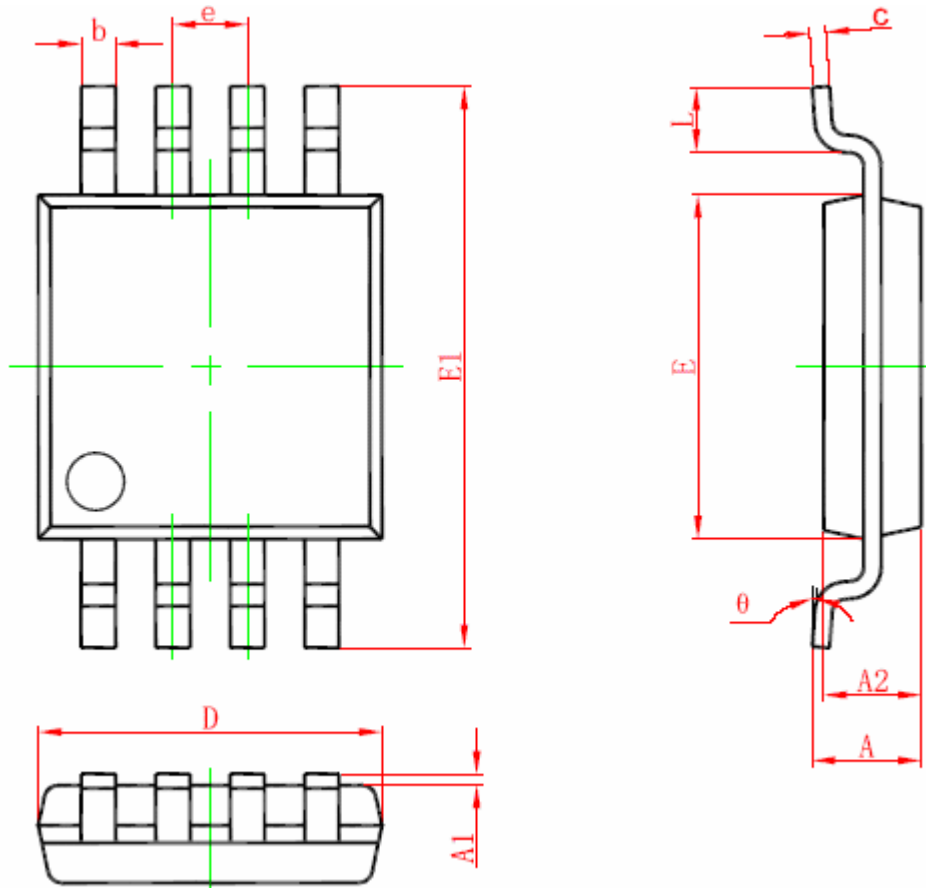
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
D	2.900	3.100	0.114	0.122
E	4.300	4.500	0.169	0.177
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
E1	6.250	6.550	0.246	0.258
A		1.100		0.043
A2	0.800	1.000	0.031	0.039
A1	0.020	0.150	0.001	0.006
e	0.65(BSC)		0.026(BSC)	
L	0.500	0.700	0.020	0.028
H	0.25(TYP)		0.01(TYP)	
	1°	7°	1°	7°

## SOP8 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
	0°	8°	0°	8°

## MSOP8 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.820	1.100	0.320	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
e	0.65(BSC)		0.026(BSC)	
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
L	0.400	0.800	0.016	0.031
$\theta$	0°	6°	0°	6°